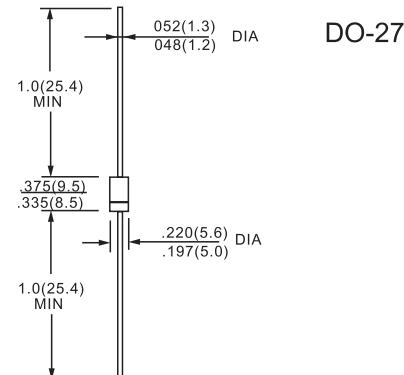


FEATURES

- 175°C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

VOLTAGE RATINGS					
PARAMETER	SYMBOL	50SQ060	50SQ080	50SQ100	UNITS
Maximum DC reverse voltage	V_R	60	80	100	V
Maximum working peak reverse voltage	V_{RWM}				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at $T_C = 119^\circ C$, rectangular waveform		5	A	
Maximum peak one cycle non-repetitive surge current See fig. 7	I_{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	1900		
		10 ms sine or 6 ms rect. pulse		290		
Non-repetitive avalanche energy	E_{AS}	$T_J = 25^\circ C$, $I_{AS} = 1.0 A$, $L = 15 mH$		7.5	mJ	
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by, T_J maximum $V_A = 1.5 \times V_R$ typical		1.0	A	

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	5 A	$T_J = 25^\circ C$	0.66	V	
		10 A		0.77		
		5 A	$T_J = 125^\circ C$	0.52		
		10 A		0.62		
Maximum reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 25^\circ C$	$V_R = \text{Rated } V_R$	0.55	mA	
		$T_J = 125^\circ C$		7		
Maximum junction capacitance	C_T	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz), $25^\circ C$		500	pF	
Typical series inductance	L_s	Measured lead to lead 5 mm from body		10	nH	
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s	

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	T_J , T_{Stg}			- 55 to 175	°C
Maximum thermal resistance, junction to lead	R_{thJL}	DC operation; see fig. 4 1/8" lead length		8.0	°C/W
Typical thermal resistance, junction to air	R_{thJA}			44	
Approximate weight				1.4	g
				0.049	oz.
Marking device		Case style DO-204AR (JEDEC)		50SQ060 50SQ080 50SQ100	



VISHAY MAS
GENERAL SEMICONDUCTOR

50SQ060 THRU 50SQ100

60V-100V 5.0A

RATINGS AND CHARACTERISTIC CURVES 50SQ060 THRU 50SQ100

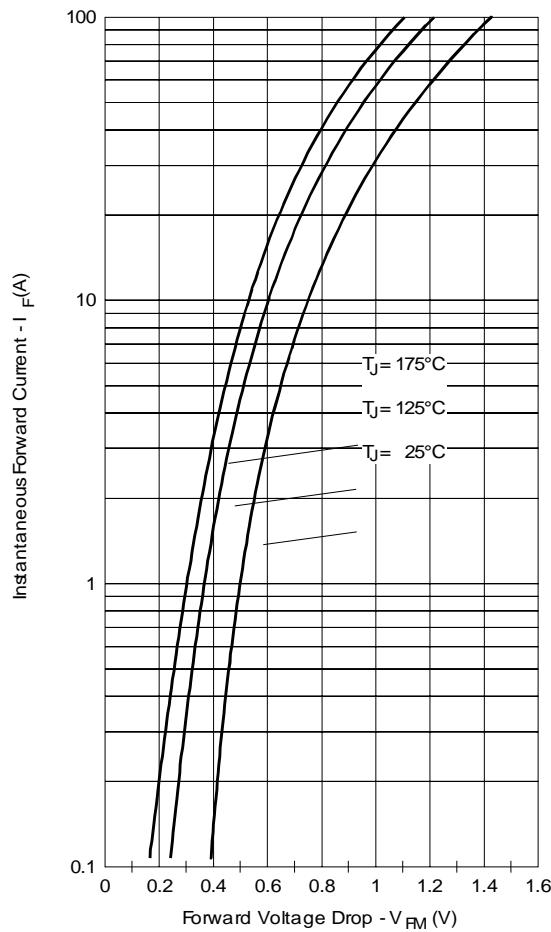


Fig. 1 - Maximum Forward Voltage Drop Characteristics

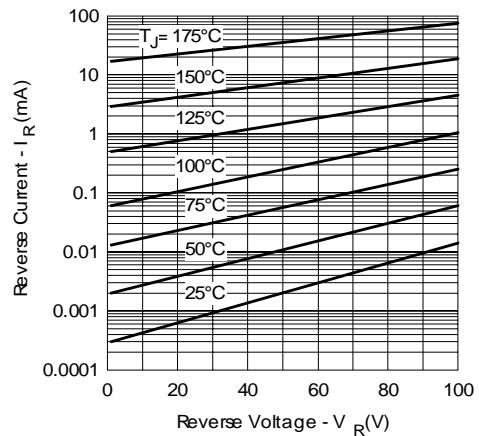


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

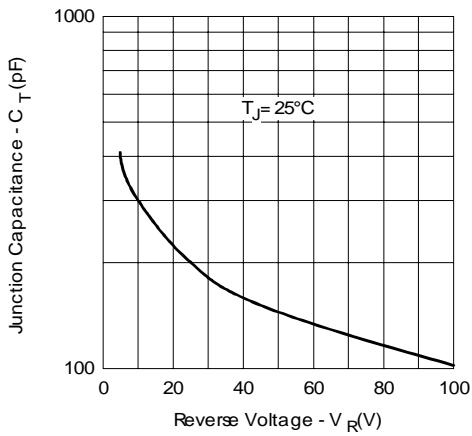


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

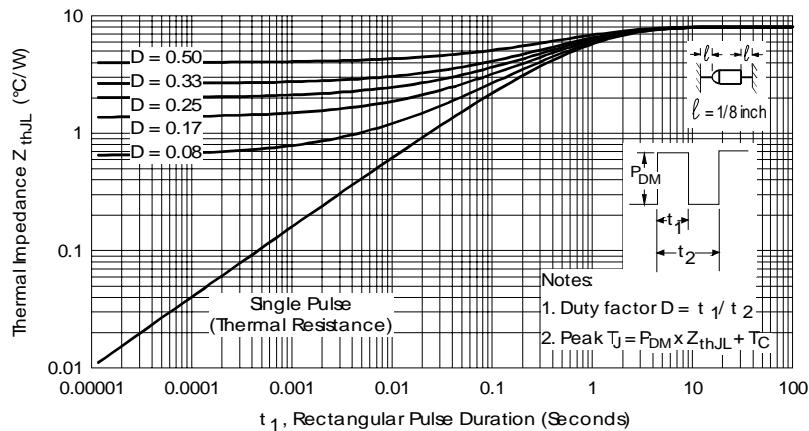


Fig. 4 - Maximum Thermal Impedance Z_{thJL} Characteristics



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60V-100V 5.0A

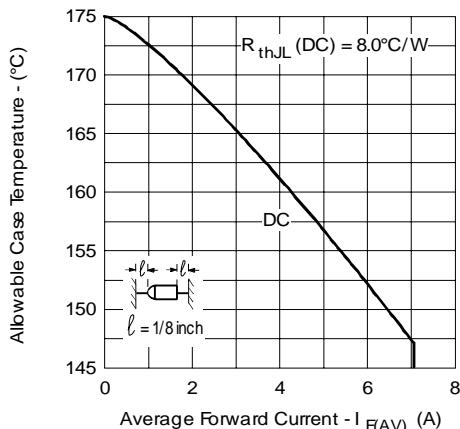


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

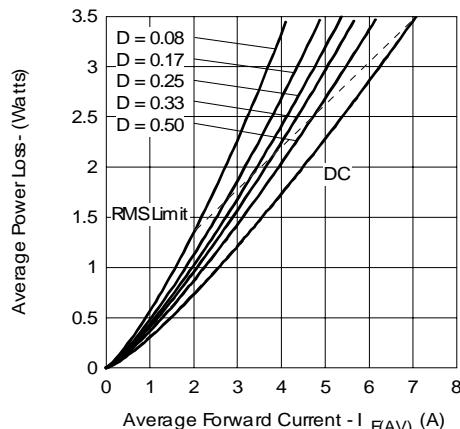


Fig. 6 - Forward Power Loss Characteristics

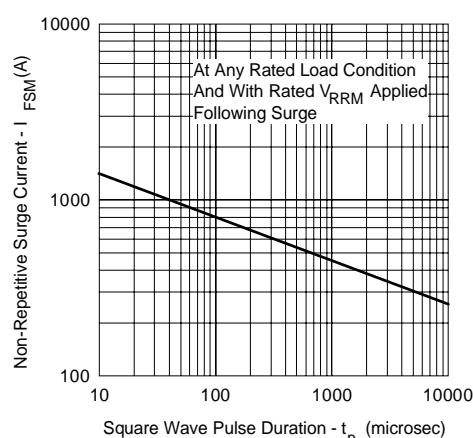


Fig. 7 - Maximum Non-Repetitive Surge Current

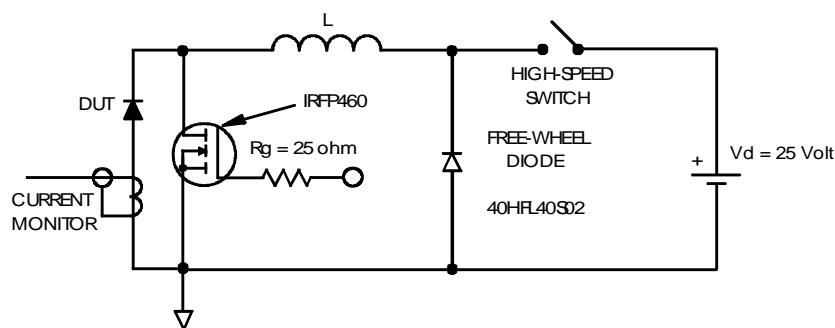


Fig. 8 - Unclamped Inductive Test Circuit